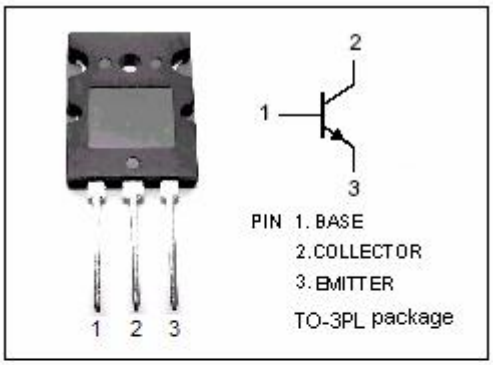
isc Silicon NPN Power Transistor MJL21194G



DESCRIPTION

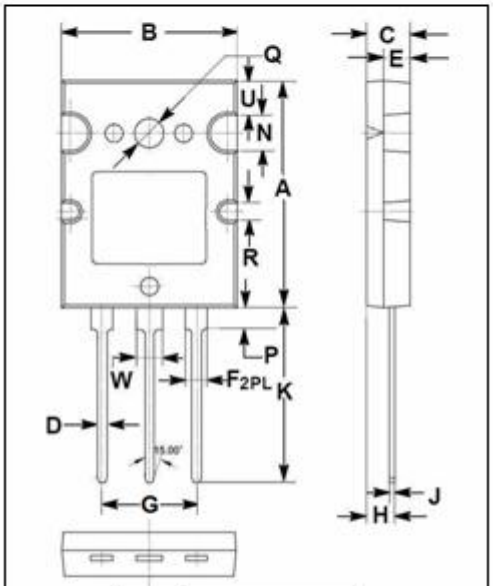
- High Collector-Emitter Breakdown Voltage-
  : V(BR)CEO= 250V(Min)
  High DC Current Gain – hFE = 25 Min @ IC = 8 Adc
- Complement to Type MJL21193
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

APPLICATIONS

Perforated Emitter technology
high power audio output, disk head positioners
linear applications

ABSOLUTE MAXIMUM RATINGS(Ta=25℃)

SYMBOL	PARAMETER	VALUE	UNIT
V_{CBO}	Collector-Base Voltage	400	V
V_{CEO}	Collector-Emitter Voltage	250	V
V_{EBO}	Emitter-Base Voltage	5	V
I_C	Collector Current-Continuous	16	A
I_B	Base Current-Continuous	5	A
P_C	Collector Power Dissipation @ T_C=25℃	200	W
T_J	Junction Temperature	150	℃
T_{stg}	Storage Temperature Range	-55~150	℃



DIM	mm MIN	MAX
A	25.50	26.50
B	19.80	20.20
C	4.50	5.50
D	0.90	1.10
E	2.80	3.20
F	2.40	2.60
G	10.80	11.00
H	3.10	3.30
J	0.50	0.70
K	20.00	21.00
N	3.90	4.50
P	2.40	2.60
Q	3.10	3.50
R	1.90	2.60
U	3.90	4.10
W	2.90	3.25

isc Silicon NPN Power Transistor MJL21194G

ELECTRICAL CHARACTERISTICS

T_C=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
$V_{(BR)CEO}$	Collector-Emitter Breakdown Voltage	I_C= 50mA; I_B= 0	250			V
$V_{CE(sat)-1}$	Collector-Emitter Saturation Voltage	I_C= 8.0A; I_B= 0.8A			1.4	V
$V_{CE(sat)-2}$	Collector-Emitter Saturation Voltage	I_C= -16A; I_B= -3.2A			4.0	V
$V_{BE(on)}$	Base-Emitter On Voltage	I_C= 8A; V_{CE}= 5V			2.2	V
I_{CEO}	Collector Cutoff Current	V_{CE}= 200V; I_E= 0			100	μA
I_{EBO}	Emitter Cutoff Current	V_{EB}= 5V; I_C= 0			100	μA
h_{FE-1}	DC Current Gain	I_C= 8A; V_{CE}= 5V	25		75	
h_{FE-2}	DC Current Gain	I_C= 16A; V_{CE}= 5V	8			
C_{OB}	Output Capacitance	I_E=0; V_{CB}= 10V; f= 1.0MHz			500	pF
f_T	Current-Gain—Bandwidth Product	I_C=1A ; V_{CE}= 10V	4			MHz
$I_{s/b}$	Second Breakdown Collector Current with Base Forward Biased	V_{CE}= 50V,t= 1.0s	4			A
		V_{CE}= 80V,t= 1.0s	2.25			A

isc Silicon NPN Power Transistor MJL21194G

NOTICE：

ISC reserves the rights to make changes of the content herein the datasheet at any time without notification. The information contained herein is presented only as a guide for the applications of our products.

ISC products are intended for usage in general electronic equipment. The products are not designed for use in equipment which require specialized quality and/or reliability, or in equipment which could have applications in hazardous environments, aerospace industry, or medical field. Please contact us if you intend our products to be used in these special applications.

ISC makes no warranty or guarantee regarding the suitability of its products for any particular purpose, nor does ISC assume any liability arising from the application or use of any products, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages.